

TOSHIBA**TD62705,706P/F**

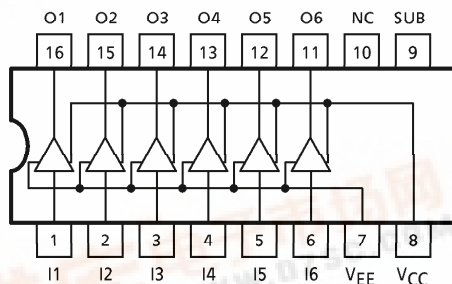
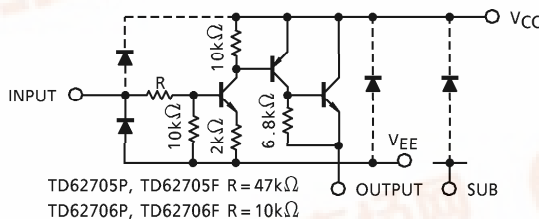
TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62705P, TD62705F, TD62706P, TD62706F**6CH HIGH-VOLTAGE SOURCE DRIVER**

The TD62705P, TD62705F and TD62706P, TD62706F are comprised of six source current transistor array. These drivers are specifically designed for fluorescent display applications. For proper operation, the substrate (SUB) must be connected to the most negative voltage.

FEATURES

- High output voltage : $V_{CC} - V_{OUT} = 60V$ (Min.)
- Output current (single output) : $I_{OUT} = -50mA$ (Max.)
- Input compatible with various types of logic
 TD62705P, TD62705F $R_{IN} = 47k\Omega$: 6~25V PMOS, CMOS
 TD62706P, TD62706F $R_{IN} = 10k\Omega$: TTL, 5V CMOS
- Package type-P : DIP-16 pin
- Package type-F : SOP-16 pin

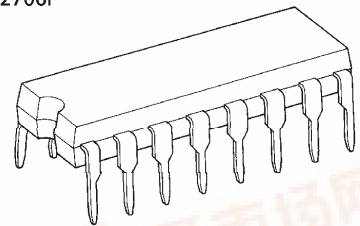
PIN CONNECTION (TOP VIEW)**SCHEMATICS (EACH DRIVER)**

(Note) The input and output parasitic diodes cannot be used as clamp diodes.

961001EBA2

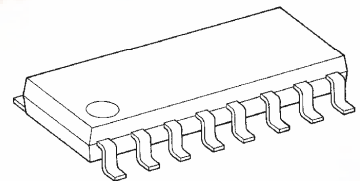
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TD62705P
TD62706P



DIP16-P-300-2.54A

TD62705F
TD62706F



SOP16-P-225-1.27

Weight

DIP16-P-300-2.54A : 1.11g (Typ.)
 SOP16-P-225-1.27 : 0.16g (Typ.)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Supply Voltage		V _{CC} -V _{EE}	30	V
		V _{CC} -V _{SUB}	60	
Output Voltage		V _{CC} -V _{OUT}	- 60	V
Input Voltage		V _{IN} -V _{EE}	V _{CC} - V _{EE}	V
Output Current		I _{OUT}	- 50	mA / ch
Input Current		I _{IN}	± 10	mA
Power Dissipation	P	P _D (Note 2)	1.0	W
	F		0.625 (Note 1)	
Operating Temperature		T _{opr}	- 40~85	°C
Storage Temperature		T _{stg}	- 55~150	°C

(Note 1) On Glass Epoxy PCB (30×30×1.6mm Cu 50%)

(Note 2) Delated above 25°C in the proportion of 8.0mw/°C (P Type), 5.0mw/°C (F Type).

RECOMMENDED OPERATING CONDITIONS (Ta = - 40~85°C)

CHARACTERISTIC		SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	TD62705P TD62705F	V _{CC}	V _{EE} = 0V	6.0	—	25	V
	TD62706P TD62706F			4.5	—	25	
		V _{SUB}	V _{CC} = 0V	V _{OUT}	—	- 55	V
Output Voltage		V _{OUT}	V _{CC} = 0V	0	—	- 55	V
Output Current		I _{OUT}	—	0	—	- 40	mA / ch
Input Voltage	TD62705P TD62705F	V _{IN}	V _{EE} = 0V, V _{CC} = 25V	0	—	25	V
	TD62706P TD62706F			0	—	7	
Power Dissipation	P	P _D	—	—	—	0.36	W
	F		On PCB (Note)	—	—	0.325	

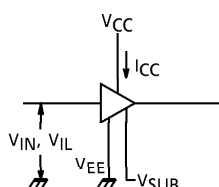
(Note) On Glass Epoxy PCB (30×30×1.6mm, Cu 50%)

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

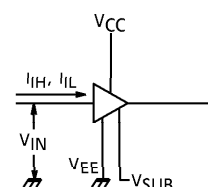
CHARACTERISTIC			SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Voltage	“H” Level	TD62705P	V _{IH}	1	V _{EE} = 0V	6.0	—	—	V
		TD62705F			V _{EE} = 0V	2.2	—	—	
	“L” Level	TD62706P	V _{IL}	1	V _{EE} = 0V	—	—	2.2	
		TD62706F			V _{EE} = 0V	—	—	0.8	
Input Current	“H” Level	TD62705P	I _{IH}	2	V _{EE} = 0V, V _{IN} = 6.0V	—	0.11	0.16	mA
		TD62705F			V _{EE} = 0V, V _{IN} = 2.4V	—	0.12	0.18	
	“L” Level	TD62706P	I _{IL}	2	V _{EE} = V _{IN} = 0V, V _{CC} = 25V	—	—	± 1	μA
Output Leakage Current			I _{CEX}	3	V _{EE} = 0V, V _{CC} = 25V V _{IN} = V _{IL} MAX. I _{OUT} = - 30V	—	—	- 100	μA
Collector-Emitter Saturation Voltage			V _{CE} (sat)	4	V _{EE} = 0V, V _{CC} = V _{CC} MIN. V _{IN} = V _{IH} MIN. I _{OUT} = - 40mA	—	—	V _{CC} - 2.5	V
Supply Current (Output On)		TD62705P	I _{CC}	1	V _{EE} = 0V, V _{CC} = 25V V _{IN} = V _{IN} MAX. I _{OUT} = 0mA	—	—	32	mA
		TD62706P				—	—	25	
Turn-On Delay			t _{ON}	5	R _L = 1.4kΩ, C _L = 15pF	—	0.2	—	μs
Turn-Off Delay			t _{OFF}			—	1.5	—	μs

TEST CIRCUIT

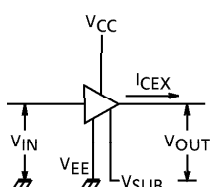
1. V_{IH} , V_{IL} , I_{CC}



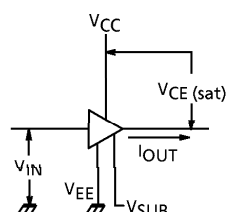
2. I_{IH} , I_{IL}



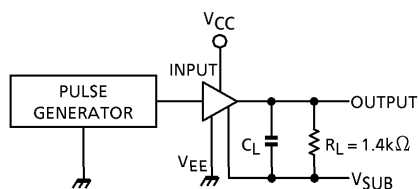
3. I_{CEX}



4. $V_{CE(sat)}$



5. t_{ON} , t_{OFF}



$C_L = 15\text{pF}$
(Includes probe and jig capacitance)

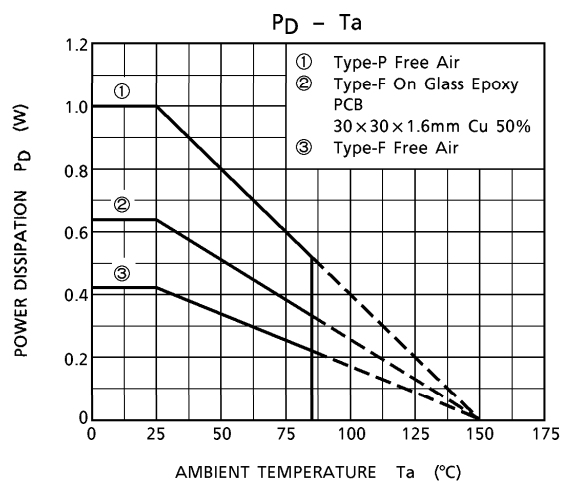
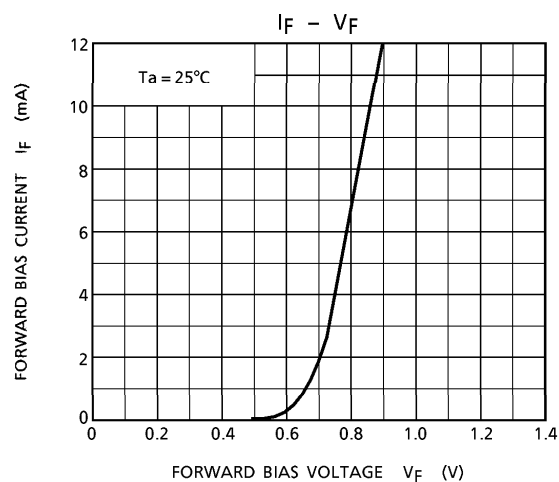
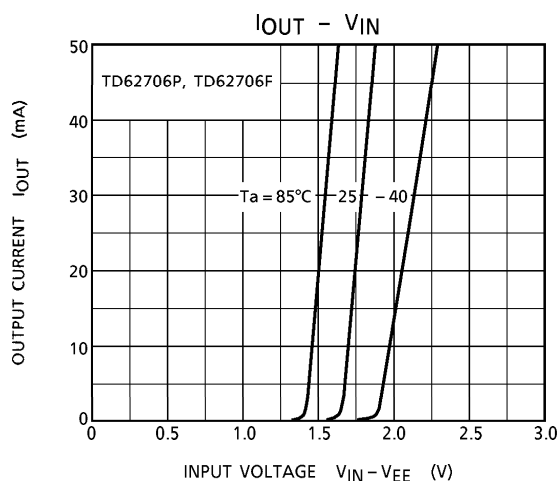
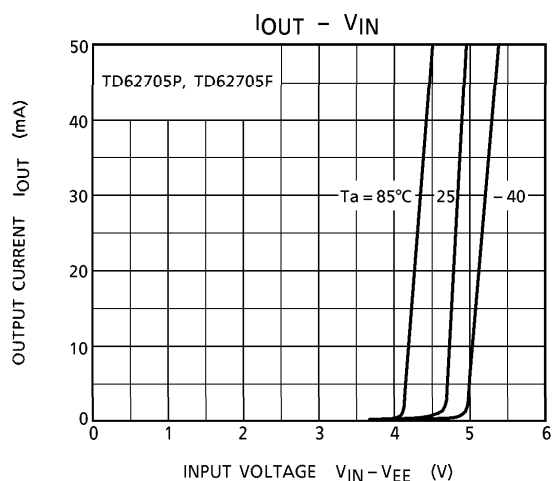
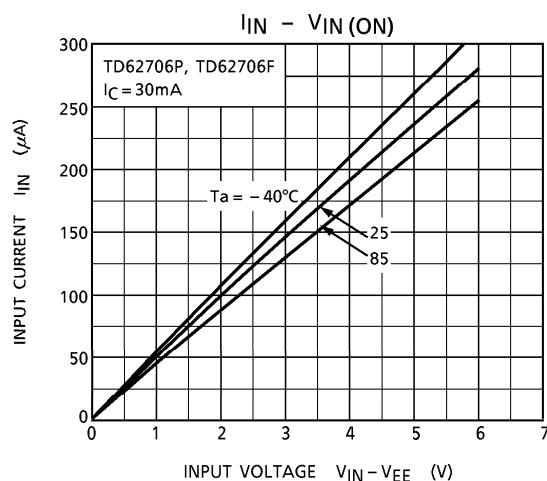
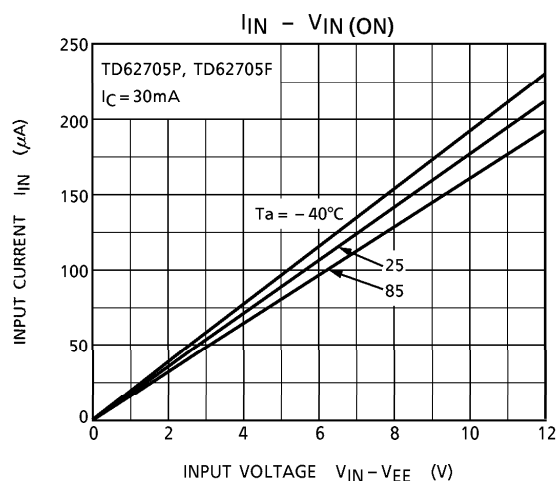
INPUT CONDITION

TYPE NAME	V_{IN}	V_{CC}	V_{SUB}
TD62705P, TD62705F	0-9V	25V	-30
TD62706P, TD62706F	0-3V	25V	-30

V_{IN} : Pulse Width $50\mu\text{s}$
Duty Cycle 50%
 $t_r \leq 5\text{ns}$
 $t_f \leq 10\text{ns}$

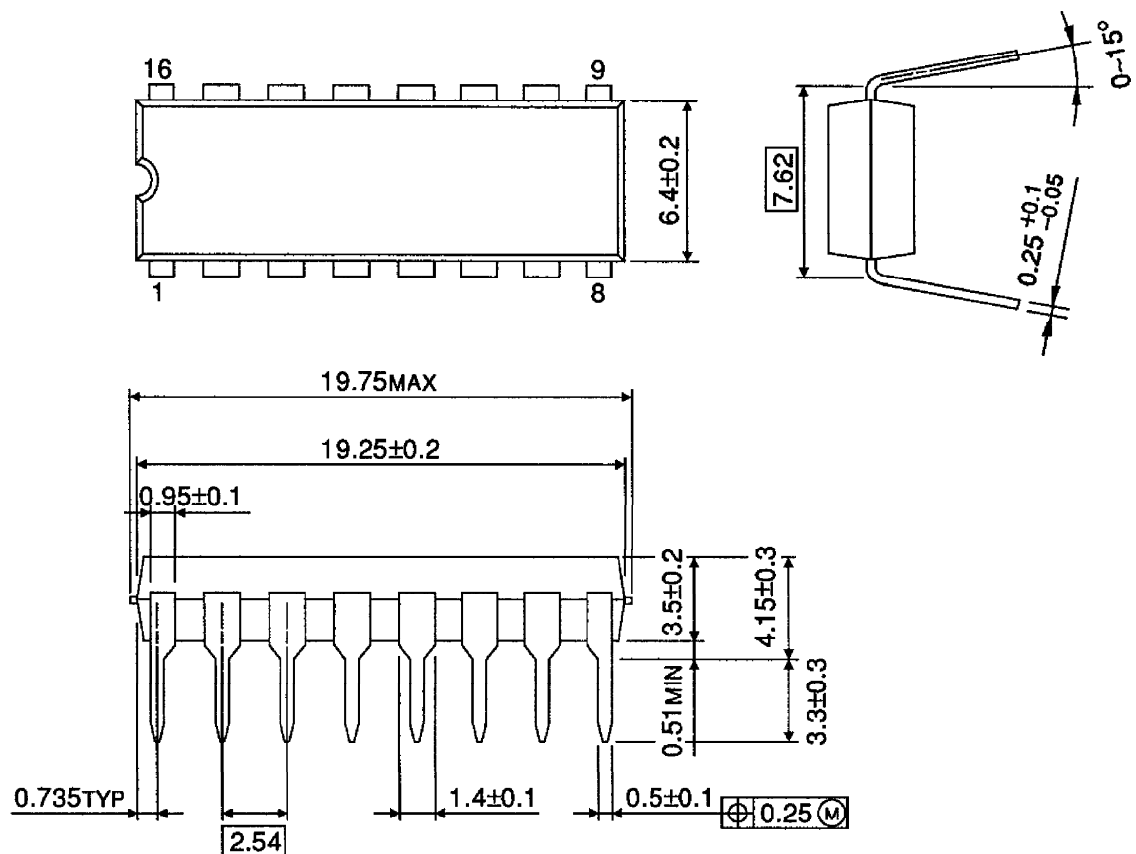
PRECAUTIONS for USING

Utmost care is necessary in the design of the output line, V_{CC} and GND (SUB, V_{EE}) line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.



OUTLINE DRAWING
DIP16-P-300-2.54A

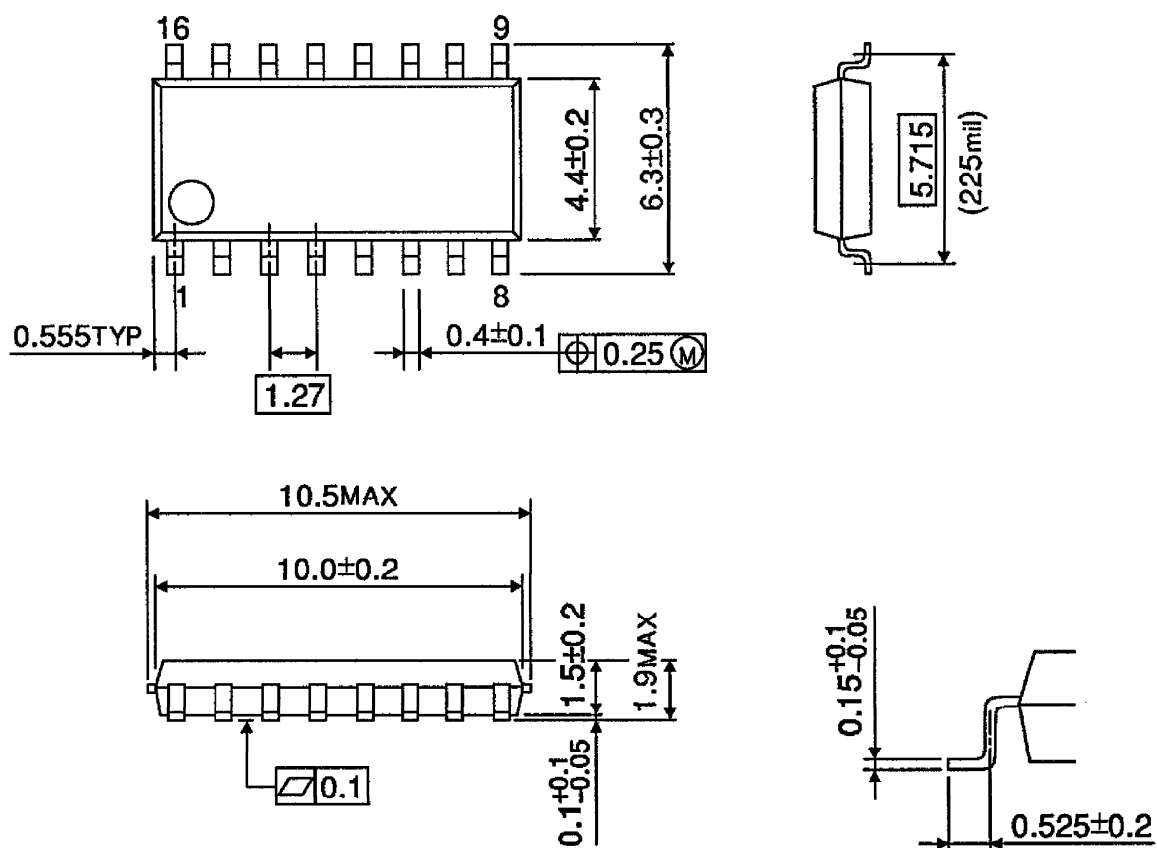
Unit : mm



Weight : 1.11g (Typ.)

OUTLINE DRAWING
SOP16-P-225-1.27

Unit : mm



Weight : 0.16g (Typ.)